

NEC

BIPOLAR ANALOG INTEGRATED CIRCUITS

μPC7800A SERIES

THREE TERMINAL POSITIVE VOLTAGE REGULATORS

DESCRIPTION

μPC7800A series are monolithic three terminal positive regulators which employ internally current limiting, thermal shut down, output transistor safe operating area protection make them essentially indestructible.

They are improved for ripple rejection ratio, line regulation, load regulation and quiescent current, as comparison of conventional μPC7800 series.

FEATURES

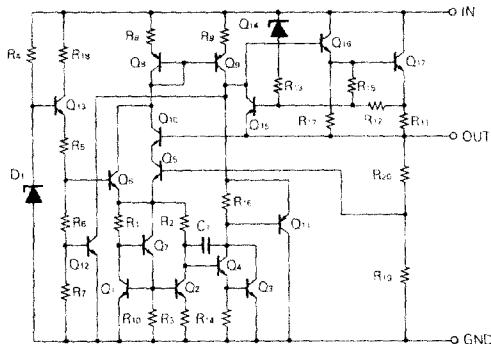
- Wide operation temperature range.
- High ripple rejection ratio.
- Good regulation (line, load).
- Low quiescent current.
- Built-in protection circuits.
(over current protection, SOA protection and thermal shut down)

ORDER INFORMATION

TYPE NUMBER	OUTPUT VOLTAGE	PACKAGE	QUALITY GRADE
μPC7805AHF	5 V		
μPC7808AHF	8 V		
μPC7893AHF	9.3 V		
μPC7812AHF	12 V	MP-45G(ISOLATED TO-220)	Standard
μPC7815AHF	15 V		
μPC7818AHF	18 V		
μPC7824AHF	24 V		

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

EQUIVALENT CIRCUIT



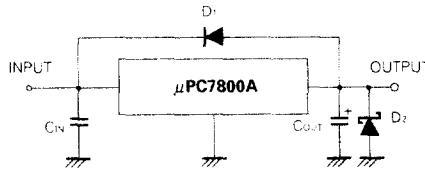
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Input Voltage	V_{IN}	35/40 (Note1)	V
Internal Power Dissipation	P_T	15 (Note2)	W
Operating Ambient Temperature Range	T_{opt}	-30 to +85	$^\circ\text{C}$
Operating Junction Temperature Range	$T_{opt(j)}$	-30 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$
Thermal Resistance (junction to case)	$R_{th(j\text{-}c)}$	5	$^\circ\text{C}/\text{W}$
Thermal Resistance (junction to ambient)	$R_{th(j\text{-}a)}$	65	$^\circ\text{C}/\text{W}$

(Note1) μ PC7805A, 08A, 93A, 12A, 15A, 18A : 35 V, μ PC7824A : 40 V

(Note2) Internally limited

TYPICAL CONNECTION

C₁: Required if regulator is located an appreciable distance from power supply filter.C₂: More than 0.1 μF D₁: Needed for $V_{IN} < V_O$ D₂: Needed for $V_O < \text{GND}$

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL		MIN.	TYP.	MAX.	UNIT
Input Voltage	V_{IN}	μ PC7805AHF	7	10	25	V
		μ PC7808AHF	10.5	14	25	
		μ PC7893AHF	12	15	24.5	
		μ PC7812AHF	14.5	19	30	
		μ PC7815AHF	17.5	23	30	
		μ PC7818AHF	21	27	33	
		μ PC7824AHF	27	33	38	
Output Current	I_O	All	0.005	0.5	1	A
Operating Junction Temperature Range	$T_{opt(j)}$	All	-30		+125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS μPC7805A

(VIN = 10 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	Tj = 25 °C	4.8	5.0	5.2	V
		7 V ≤ VIN ≤ 20 V, 5 mA ≤ IO ≤ 1 A, P ≤ 15 W	4.75		5.25	
		-30 °C ≤ TJ ≤ +125 °C	4.75		5.25	
Line Regulation	REGIN	Tj = 25 °C, 7 V ≤ VIN ≤ 25 V		7	30	mV
		Tj = 25 °C, 8 V ≤ VIN ≤ 12 V		2	15	
Load Regulation	REGL	Tj = 25 °C, 5 mA ≤ IO ≤ 1.5 A		4	30	mV
		Tj = 25 °C, 250 mA ≤ IO ≤ 750 mA		2	10	
Quiescent Current	IBIAS	Tj = 25 °C		2.8	4.3	mA
Quiescent Current Change	ΔIBIAS	7 V ≤ VIN ≤ 25 V			1.0	mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	Vn	Tj = 25 °C, 10 Hz ≤ f ≤ 100 kHz		40	200	μV _{r.m.s.}
Ripple Rejection	R+R	Tj = 25 °C, f = 120 Hz, 8 V ≤ VIN ≤ 18 V	70	76		dB
Dropout Voltage	VDF	Tj = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	ICshort	Tj = 25 °C, VIN = 25 V		1.6		A
Peak Output Current	IOPeak	Tj = 25 °C, VIN = 10 V		1.7	2.2	A
Temperature Coefficient of Output Voltage	AVo/AT	IO = 5 mA, 0 °C ≤ TJ ≤ +125 °C		-0.4		mV/°C

ELECTRICAL CHARACTERISTICS μPC7808A

(VIN = 14 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	Tj = 25 °C	7.7	8.0	8.3	V
		10.5 V ≤ VIN ≤ 23 V, 5 mA ≤ IO ≤ 1 A, P ≤ 15 W	7.6		8.4	
		-30 °C ≤ TJ ≤ +125 °C	7.6		8.4	
Line Regulation	REGIN	Tj = 25 °C, 10.5 V ≤ VIN ≤ 25 V		8	35	mV
		Tj = 25 °C, 11 V ≤ VIN ≤ 17 V		3	25	
Load Regulation	REGL	Tj = 25 °C, 5 mA ≤ IO ≤ 1.5 A		12	90	mV
		Tj = 25 °C, 250 mA ≤ IO ≤ 750 mA		4	20	
Quiescent Current	IBIAS	Tj = 25 °C		3	4.4	mA
Quiescent Current Change	ΔIBIAS	10.5 V ≤ VIN ≤ 25 V			1.0	mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	Vn	Tj = 25 °C, 10 Hz ≤ f ≤ 100 kHz		50	250	μV _{r.m.s.}
Ripple Rejection	R+R	Tj = 25 °C, f = 120 Hz, 11.5 V ≤ VIN ≤ 21.5 V	66	72		dB
Dropout Voltage	VDF	Tj = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	ICshort	Tj = 25 °C, VIN = 25 V		1.6		A
Peak Output Current	IOPeak	Tj = 25 °C, VIN = 14 V		1.7	2.2	A
Temperature Coefficient of Output Voltage	AVo/AT	IO = 5 mA, 0 °C ≤ TJ ≤ +125 °C		-0.6		mV/°C

ELECTRICAL CHARACTERISTICS μ PC7812A

(VIN = 19 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	T _j = 25 °C	11.5	12.0	12.5	V
		14.5 V ≤ VIN ≤ 27 V, 5 mA ≤ IO ≤ 1 A, PR ≤ 15 W	11.4		12.6	
		-30 °C ≤ T _j ≤ +125 °C	11.4		12.6	
Line Regulation	REG _{IN}	T _j = 25 °C, 14.5 V ≤ VIN ≤ 30 V		10	45	mV
		T _j = 25 °C, 16 V ≤ VIN ≤ 22 V		4	30	
Load Regulation	REG _L	T _j = 25 °C, 5 mA ≤ IO ≤ 1.5 A		17	130	mV
		T _j = 25 °C, 250 mA ≤ IO ≤ 750 mA		6	30	
Quiescent Current	I _{BIAS}	T _j = 25 °C		3.1	4.6	mA
Quiescent Current Change	ΔI _{BIAS}	14.5 V ≤ VIN ≤ 30 V			1.0	mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	V _n	T _j = 25 °C, 10 Hz ≤ f ≤ 100 kHz		70	300	μV _{r.m.s.}
Ripple Rejection	R·R	T _j = 25 °C, f = 120 Hz, 15 V ≤ VIN ≤ 25 V	62	68		dB
Dropout Voltage	V _{DIF}	T _j = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	I _{Oshort}	T _j = 25 °C, VIN = 30 V		1.3		A
Peak Output Current	I _{Opeak}	T _j = 25 °C, VIN = 19 V	1.7	2.2	2.8	A
Temperature Coefficient of Output Voltage	ΔVO/ΔT	IO = 5 mA, 0 °C ≤ T _j ≤ +125 °C		-0.8		mV/°C

ELECTRICAL CHARACTERISTICS μ PC7815A

(VIN = 23 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	T _j = 25 °C	14.4	15.0	15.6	V
		17.5 V ≤ VIN ≤ 30 V, 5 mA ≤ IO ≤ 1 A, PR ≤ 15 W	14.25		15.75	
		-30 °C ≤ T _j ≤ +125 °C	14.25		15.75	
Line Regulation	REG _{IN}	T _j = 25 °C, 17.5 V ≤ VIN ≤ 30 V		10	45	mV
		T _j = 25 °C, 20 V ≤ VIN ≤ 26 V		5	35	
Load Regulation	REG _L	T _j = 25 °C, 5 mA ≤ IO ≤ 1.5 A		25	190	mV
		T _j = 25 °C, 250 mA ≤ IO ≤ 750 mA		8	40	
Quiescent Current	I _{BIAS}	T _j = 25 °C		3.3	4.8	mA
Quiescent Current Change	ΔI _{BIAS}	17.5 V ≤ VIN ≤ 30 V			1.0	mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	V _n	T _j = 25 °C, 10 Hz ≤ f ≤ 100 kHz		85	400	μV _{r.m.s.}
Ripple Rejection	R·R	T _j = 25 °C, f = 120 Hz, 18.5 V ≤ VIN ≤ 28.5 V	60	66		dB
Dropout Voltage	V _{DIF}	T _j = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	I _{Oshort}	T _j = 25 °C, VIN = 30 V		1.3		A
Peak Output Current	I _{Opeak}	T _j = 25 °C, VIN = 23 V	1.7	2.2	2.8	A
Temperature Coefficient of Output Voltage	ΔVO/ΔT	IO = 5 mA, 0 °C ≤ T _j ≤ +125 °C		-1.1		mV/°C

ELECTRICAL CHARACTERISTICS μ PC7818A

(VIN = 27 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	Tj = 25 °C	17.3	18.0	18.7	V
		21 V ≤ VIN ≤ 33 V, 5 mA ≤ IO ≤ 1 A, PT ≤ 15 W	17.1	18.9		
		- 30 °C ≤ TJ ≤ + 125 °C	17.1		18.9	
Line Regulation	REGIN	Tj = 25 °C, 21 V ≤ VIN ≤ 33 V		12	60	mV
		Tj = 25 °C, 24 V ≤ VIN ≤ 30 V		6	45	
Load Regulation	REGL	Tj = 25 °C, 5 mA ≤ IO ≤ 1.5 A		32	110	mV
		Tj = 25 °C, 250 mA ≤ IO ≤ 750 mA		10	40	
Quiescent Current	I _{BIAS}	Tj = 25 °C		3.4	5.0	mA
Quiescent Current Change	ΔIBIAS	21 V ≤ VIN ≤ 33 V		1.0		mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	V _n	Tj = 25 °C, 10 Hz ≤ f ≤ 100 kHz		95	450	μV _{r.m.s.}
Ripple Rejection	R _R	Tj = 25 °C, f = 120 Hz, 22 V ≤ VIN ≤ 32 V	59	65		dB
Dropout Voltage	V _{DIF}	Tj = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	I _{short}	Tj = 25 °C, VIN = 33 V		1.2		A
Peak Output Current	I _{peak}	Tj = 25 °C, VIN = 27 V	1.7	2.2	2.8	A
Temperature Coefficient of Output Voltage	ΔVO/ΔT	IO = 5 mA, 0 °C ≤ TJ ≤ + 125 °C		- 1.3		mV/°C

ELECTRICAL CHARACTERISTICS μ PC7824A

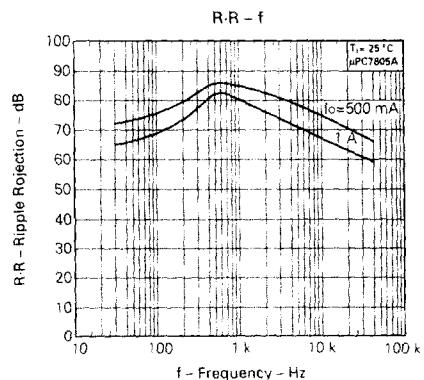
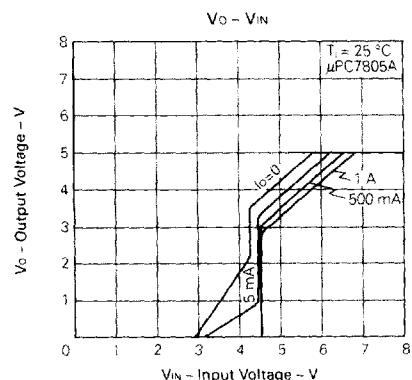
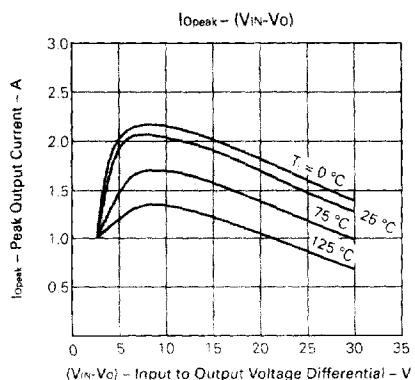
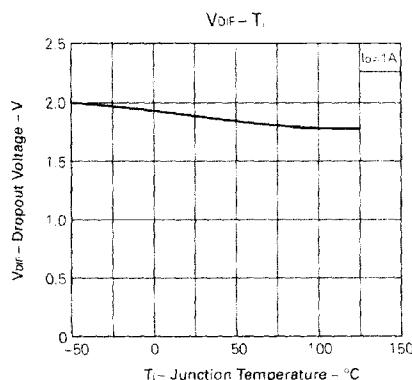
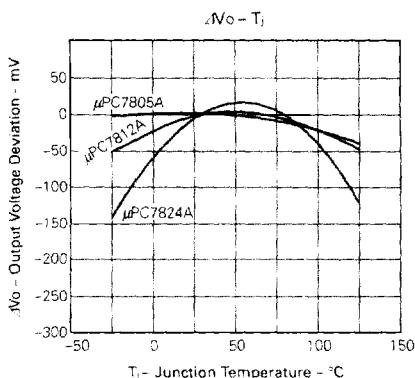
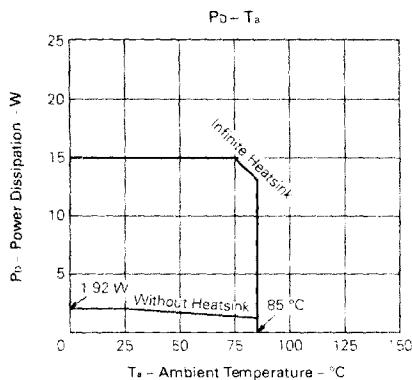
(VIN = 33 V, IO = 500 mA, 0 °C ≤ TJ ≤ + 125 °C)

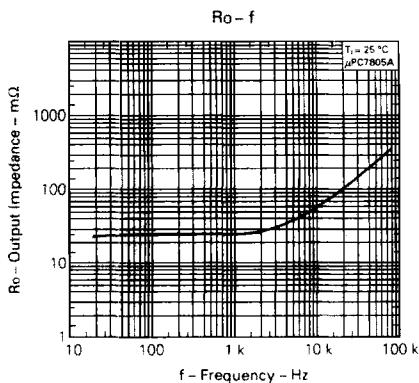
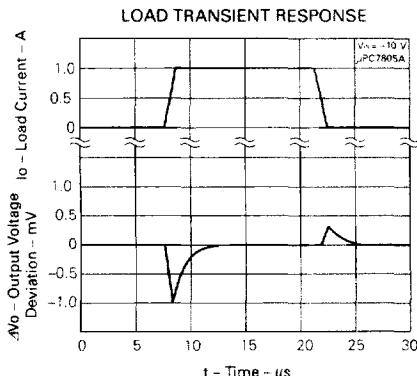
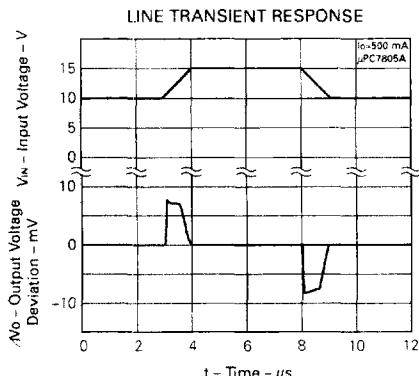
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	Tj = 25 °C	23.0	24.0	25.0	V
		27 V ≤ VIN ≤ 38 V, 5 mA ≤ IO ≤ 1 A, PT ≤ 15 W	22.8	25.2		
		- 30 °C ≤ TJ ≤ + 125 °C	22.8		25.2	
Line Regulation	REGIN	Tj = 25 °C, 27 V ≤ VIN ≤ 38 V		15	80	mV
		Tj = 25 °C, 30 V ≤ VIN ≤ 36 V		8	50	
Load Regulation	REGL	Tj = 25 °C, 5 mA ≤ IO ≤ 1.5 A		44	150	mV
		Tj = 25 °C, 250 mA ≤ IO ≤ 750 mA		14	50	
Quiescent Current	I _{BIAS}	Tj = 25 °C		3.6	5.3	mA
Quiescent Current Change	ΔIBIAS	27 V ≤ VIN ≤ 38 V		1.0		mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	V _n	Tj = 25 °C, 10 Hz ≤ f ≤ 100 kHz		120	500	μV _{r.m.s.}
Ripple Rejection	R _R	Tj = 25 °C, f = 120 Hz, 28 V ≤ VIN ≤ 38 V	55	62		dB
Dropout Voltage	V _{DIF}	Tj = 25 °C, IO = 1.0 A		2.0		V
Short Circuit Current	I _{short}	Tj = 25 °C, VIN = 38 V		1.0		A
Peak Output Current	I _{peak}	Tj = 25 °C, VIN = 33 V	1.7	2.2	2.8	A
Temperature Coefficient of Output Voltage	ΔVO/ΔT	IO = 5 mA, 0 °C ≤ TJ ≤ + 125 °C		- 1.7		mV/°C

ELECTRICAL CHARACTERISTICS μ PC7893A

(VIN = 15 V, IO = 500 mA, 0°C ≤ TJ ≤ +125°C)

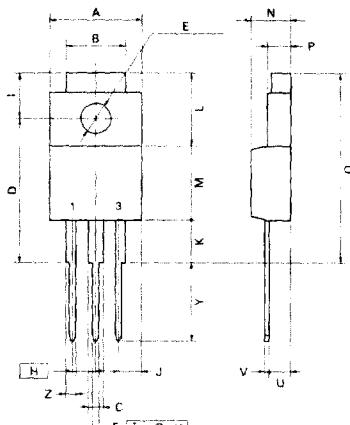
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	VO	T _j = 25 °C	9.0	9.3	9.5	V
		12 V ≤ VIN ≤ 24.5 V, 5 mA ≤ IO ≤ 1 A, P _T ≤ 15 W	8.9		9.7	
		-30 °C ≤ T _j ≤ +125 °C	8.9		9.7	
Line Regulation	REG _{IN}	T _j = 25 °C, 12 V ≤ VIN ≤ 26.5 V		9	40	mV
		T _j = 25 °C, 12.5 V ≤ VIN ≤ 18.5 V		4	30	
Load Regulation	REG _L	T _j = 25 °C, 5 mA ≤ IO ≤ 1.5 A		15	110	mV
		T _j = 25 °C, 250 mA ≤ IC ≤ 750 mA		5	25	
Quiescent Current	I _{BIAS}	T _j = 25 °C		3.1	4.5	mA
Quiescent Current Change	ΔI _{BIAS}	12 V ≤ VIN ≤ 26.5 V			1.0	mA
		5 mA ≤ IO ≤ 1.0 A			0.5	
Output Noise Voltage	V _r	T _j = 25 °C, 10 Hz ≤ f ≤ 100 kHz		55	230	μV _{r.m.s.}
Ripple Rejection	R+R	T _j = 25 °C, f = 120 Hz, 12.5 V ≤ VIN ≤ 22.5 V	64	70		dB
Dropout Voltage	V _{DIF}	T _j = 25 °C, IO = 1.0 A		1.8		V
Short Circuit Current	I _{Oshort}	T _j = 25 °C, VIN = 26.5 V		1.5		A
Peak Output Current	I _{Opeak}	T _j = 25 °C, VIN = 15 V	1.7	2.2	2.8	A
Temperature Coefficient of Output Voltage	ΔVO/ΔT	IO = 5 mA, 0 °C ≤ T _j ≤ +125 °C		-0.7		mV/°C

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



PACKAGE DIMENSIONS

3PIN PLASTIC SIP (MP-45G)



P3HF-254B-1

NOTE

Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	10.4 MAX.	0.410 MAX.
B	7.0	0.276
C	1.2 MIN.	0.047 MIN.
D	$17.0^{+0.3}$	$0.669^{+0.012}$
E	$\phi 3.3^{+0.2}$	$\phi 0.130^{+0.006}$
F	$0.75^{+0.10}$	$0.030^{+0.006}$
G	0.25	0.010
H	2.54 (T.P.)	0.100 (T.P.)
I	$5.0^{-0.3}$	$0.197^{-0.012}$
J	2.66 MAX.	0.105 MAX.
K	4.8 MIN	0.188 MIN.
L	8.5	0.335
M	8.5	0.335
N	$4.5^{+0.2}$	$0.177^{+0.008}$
P	$2.8^{+0.2}$	$0.110^{+0.008}$
Q	22.4 MAX.	0.882 MAX.
U	$2.4^{-0.5}$	$0.094^{-0.020}$
V	$0.65^{+0.10}$	$0.026^{+0.006}$
Y	$8.9^{+0.7}$	$0.350^{+0.028}$
Z	1.0 MIN	0.039 MIN.

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF THROUGH HOLE MOUNT DEVICE

μ PC7800AHF Series

Soldering process	Soldering conditions	Symbol
Wave soldering	Solder temperature : 260 °C or below. Flow time : 10 seconds or below.	